

MOSFETs Silicon N-channel MOS (U-MOSIX-H)

TPH2R104PL

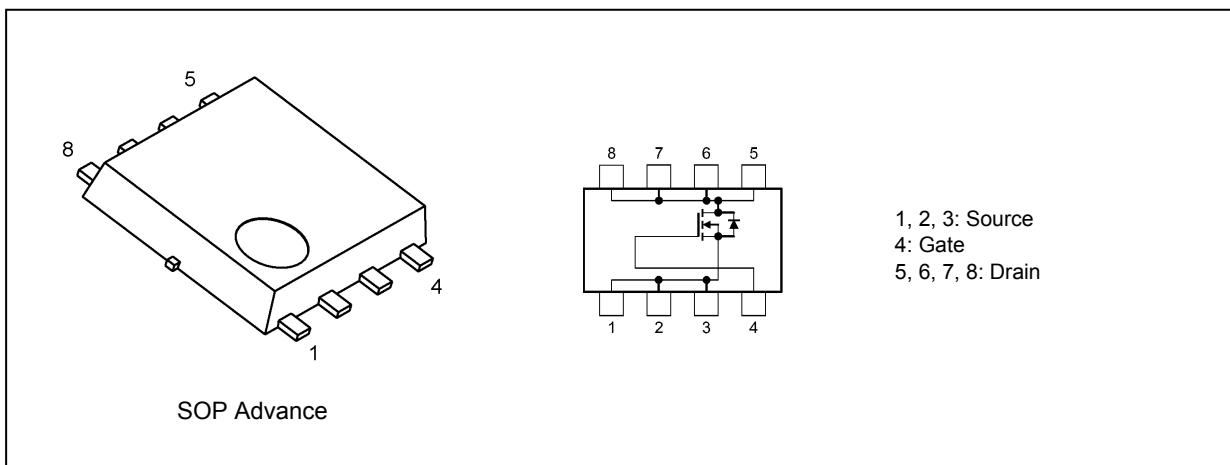
1. Applications

- High-Efficiency DC-DC Converters
- Switching Voltage Regulators
- Motor Drivers

2. Features

- (1) High-speed switching
- (2) Small gate charge : $Q_{SW} = 21 \text{ nC}$ (typ.)
- (3) Small output charge : $Q_{oss} = 46 \text{ nC}$ (typ.)
- (4) Low drain-source on-resistance : $R_{DS(ON)} = 1.6 \text{ m}\Omega$ (typ.) ($V_{GS} = 10 \text{ V}$)
- (5) Low leakage current : $I_{DSS} = 10 \mu\text{A}$ (max) ($V_{DS} = 40 \text{ V}$)
- (6) Enhancement mode : $V_{th} = 1.4$ to 2.4 V ($V_{DS} = 10 \text{ V}$, $I_D = 0.5 \text{ mA}$)

3. Packaging and Internal Circuit



Start of commercial production
2016-06

4. Absolute Maximum Ratings (Note) ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	40	V
Gate-source voltage	V_{GSS}	± 20	
Drain current (DC) ($T_c = 25^\circ\text{C}$) (Note 1)	I_D	100	A
Drain current (DC) (Silicon limit) (Note 1), (Note 2)	I_D	180	
Drain current (pulsed) ($t = 100\ \mu\text{s}$) (Note 1)	I_{DP}	200	
Power dissipation ($T_c = 25^\circ\text{C}$)	P_D	116	W
Power dissipation (Note 3)	P_D	1.8	
Power dissipation (Note 4)	P_D	0.83	
Single-pulse avalanche energy	E_{AS}	68	mJ
Single-pulse avalanche current	I_{AS}	100	A
Channel temperature	T_{ch}	175	°C
Storage temperature	T_{stg}	-55 to 175	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance ($T_c = 25^\circ\text{C}$)	$R_{th(ch-c)}$	1.29	°C/W
Channel-to-ambient thermal resistance ($T_a = 25^\circ\text{C}$) (Note 3)	$R_{th(ch-a)}$	83	
Channel-to-ambient thermal resistance ($T_a = 25^\circ\text{C}$) (Note 4)	$R_{th(ch-a)}$	180	

Note 1: Ensure that the channel temperature does not exceed 175 °C.

Note 2: Limited 100 A by package capability.

Note 3: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 4: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 5: $V_{DD} = 32\text{ V}$, $T_{ch} = 25^\circ\text{C}$ (initial), $L = 5.3\ \mu\text{H}$, $I_{AS} = 100\text{ A}$

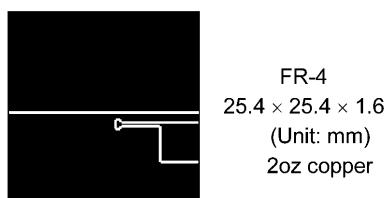


Fig. 5.1 Device Mounted on a Glass-Epoxy Board (a)

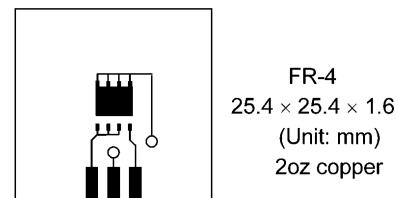


Fig. 5.2 Device Mounted on a Glass-Epoxy Board (b)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	$V_{GS} = \pm 20\text{ V}$, $V_{DS} = 0\text{ V}$	—	—	± 0.1	μA
Drain cut-off current	I_{DSS}	$V_{DS} = 40\text{ V}$, $V_{GS} = 0\text{ V}$	—	—	10	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 10\text{ mA}$, $V_{GS} = 0\text{ V}$	40	—	—	
	$V_{(BR)DSX}$	$I_D = 10\text{ mA}$, $V_{GS} = -20\text{ V}$	25	—	—	V
Gate threshold voltage	V_{th}	$V_{DS} = 10\text{ V}$, $I_D = 0.5\text{ mA}$	1.4	—	2.4	
Drain-source on-resistance	$R_{DS(\text{ON})}$	$V_{GS} = 4.5\text{ V}$, $I_D = 50\text{ A}$	—	2.2	3.1	$\text{m}\Omega$
		$V_{GS} = 10\text{ V}$, $I_D = 50\text{ A}$	—	1.6	2.1	

6.2. Dynamic Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	C_{iss}	$V_{DS} = 20\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$	—	4790	6230	pF
Reverse transfer capacitance	C_{rss}		—	70	130	
Output capacitance	C_{oss}		—	1050	—	
Gate resistance	r_g	See Figure 6.2.1	—	1.0	1.5	Ω
Switching time (rise time)	t_r		—	8.5	—	ns
Switching time (turn-on time)	t_{on}		—	24	—	
Switching time (fall time)	t_f		—	8.7	—	
Switching time (turn-off time)	t_{off}		—	47	—	

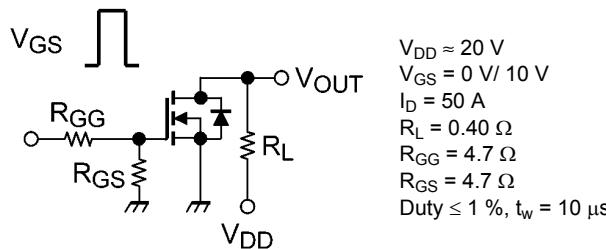


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Q_g	$V_{DD} \approx 20\text{ V}$, $V_{GS} = 10\text{ V}$, $I_D = 50\text{ A}$	—	78	—	nC
		$V_{DD} \approx 20\text{ V}$, $V_{GS} = 4.5\text{ V}$, $I_D = 50\text{ A}$	—	37	—	
Gate-source charge 1	Q_{gs1}	$V_{DD} \approx 20\text{ V}$, $V_{GS} = 10\text{ V}$, $I_D = 50\text{ A}$	—	19	—	
Gate-drain charge	Q_{gd}		—	10	—	
Gate switch charge	Q_{sw}		—	21	—	
Output charge	Q_{oss}	$V_{DS} = 20\text{ V}$, $V_{GS} = 0\text{ V}$	—	46	—	

6.4. Source-Drain Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse drain current (pulsed) (Note 6)	I_{DRP}	($t = 100\text{ }\mu\text{s}$)	—	—	200	A
Diode forward voltage	V_{DSF}	$I_{DR} = 100\text{ A}$, $V_{GS} = 0\text{ V}$	—	—	-1.2	V
Reverse recovery time	t_{rr}	$V_R = 20\text{ V}$, $I_{DR} = 25\text{ A}$, $V_{GS} = 0\text{ V}$, $-\frac{dI_{DR}}{dt} = 100\text{ A}/\mu\text{s}$	—	44	—	ns
Reverse recovery charge	Q_{rr}		—	42	—	nC

Note 6: Ensure that the channel temperature does not exceed 175 °C.

7. Marking

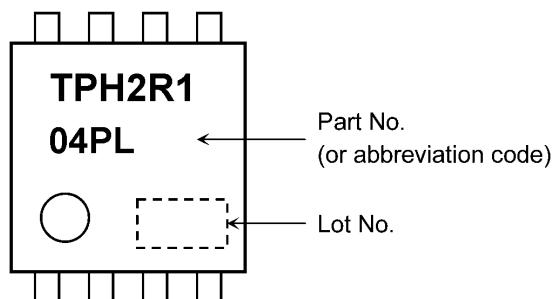


Fig. 7.1 Marking

8. Characteristics Curves (Note)

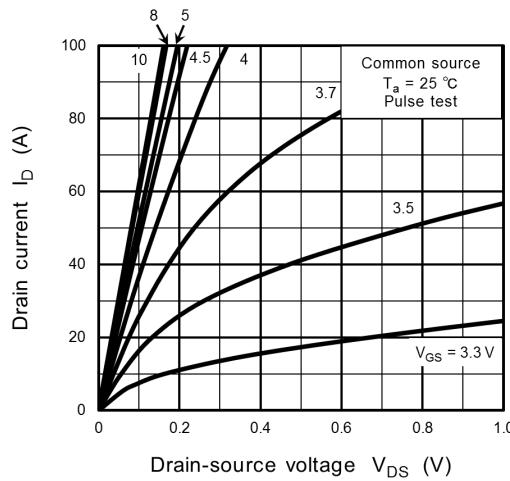


Fig. 8.1 I_D - V_{DS}

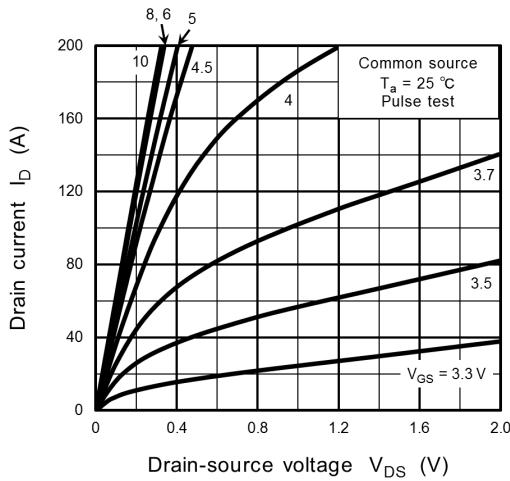


Fig. 8.2 I_D - V_{DS}

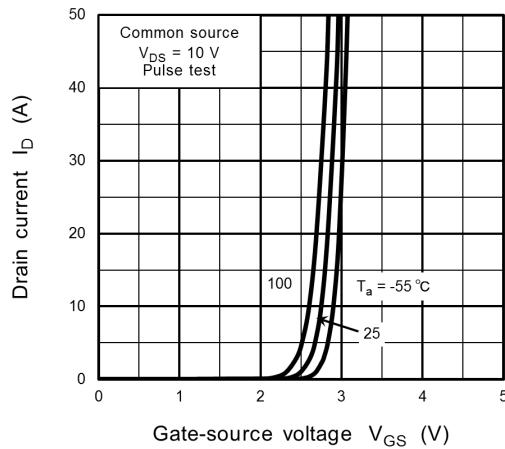


Fig. 8.3 I_D - V_{GS}

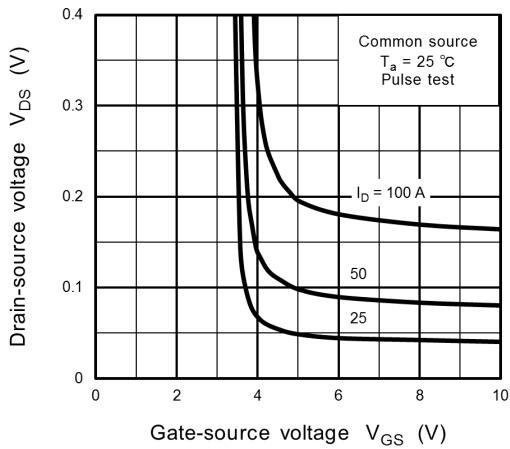


Fig. 8.4 V_{DS} - V_{GS}

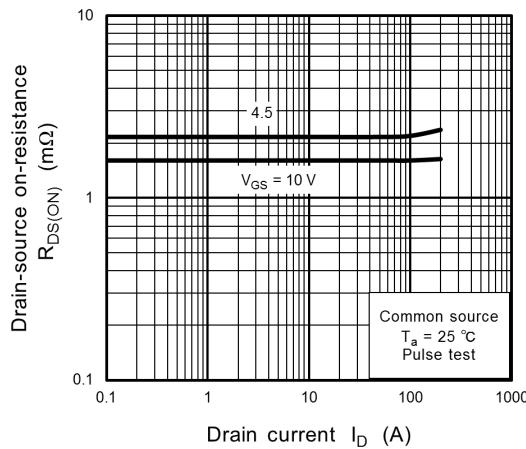


Fig. 8.5 $R_{DS(ON)}$ - I_D

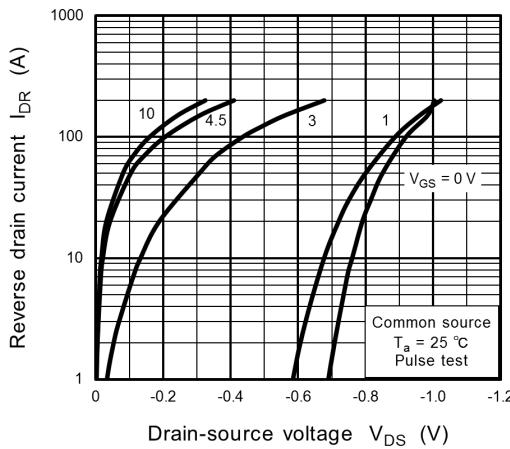


Fig. 8.6 I_{DR} - V_{DS}

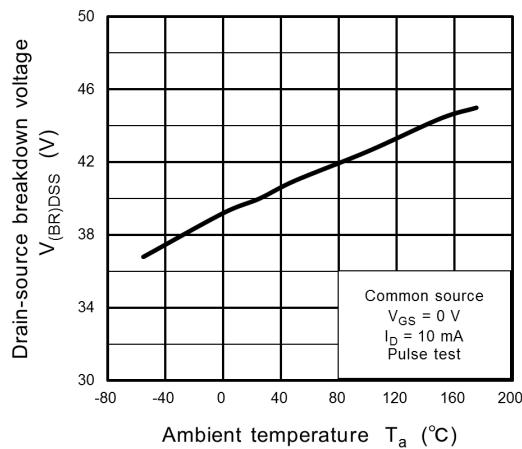
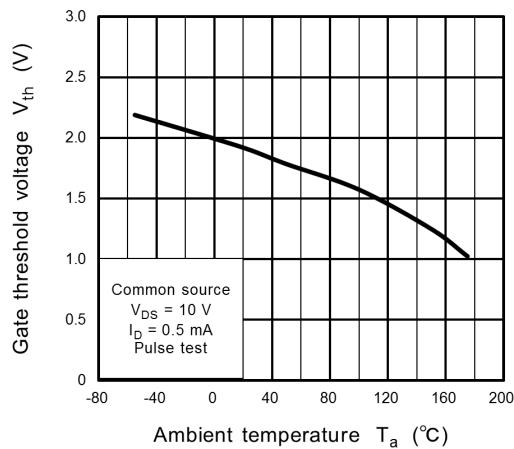
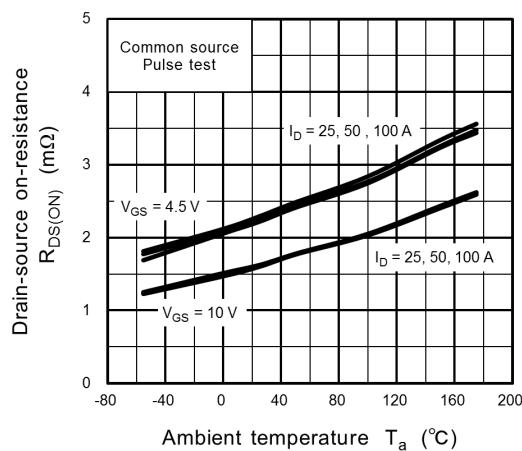
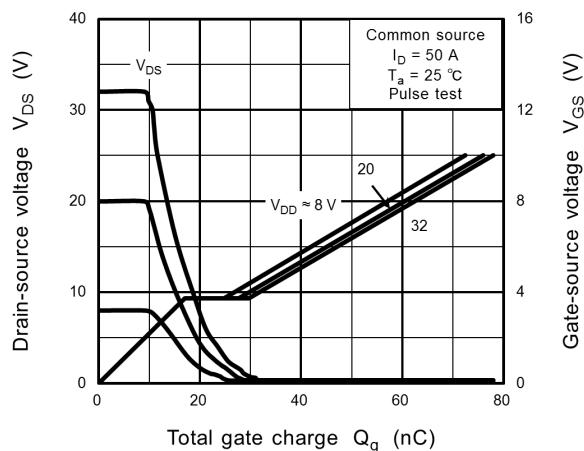
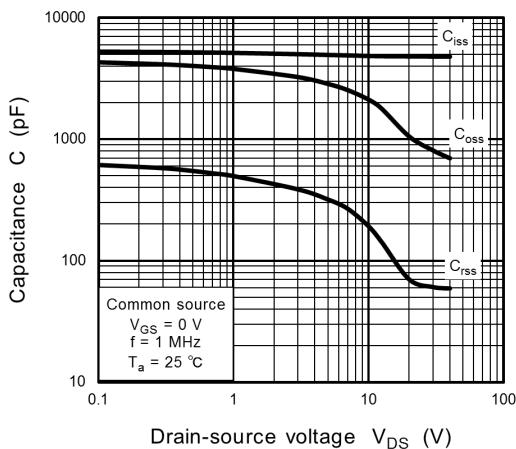
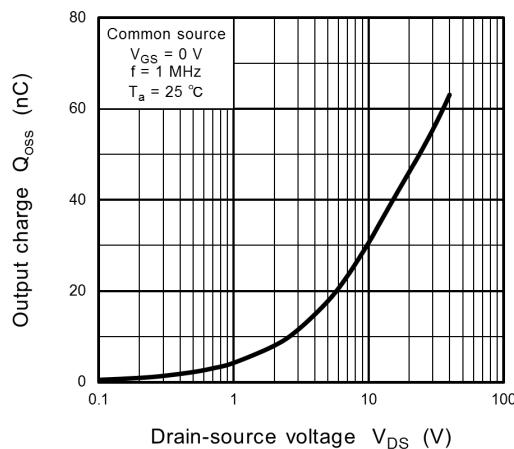
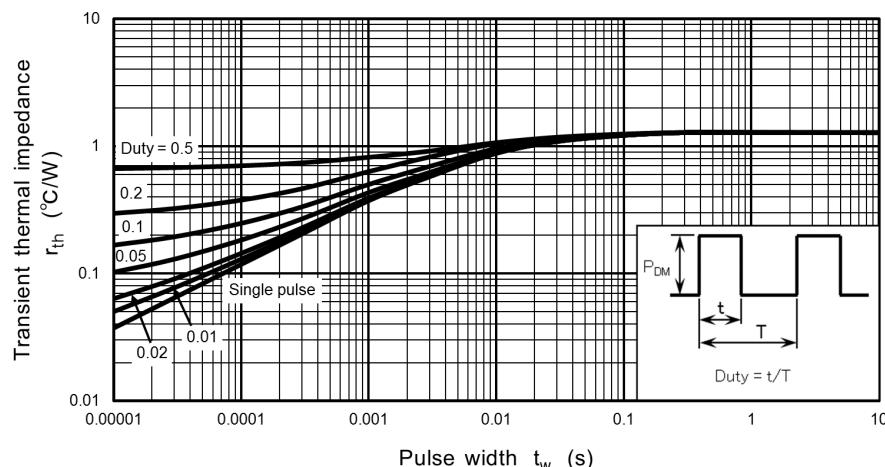
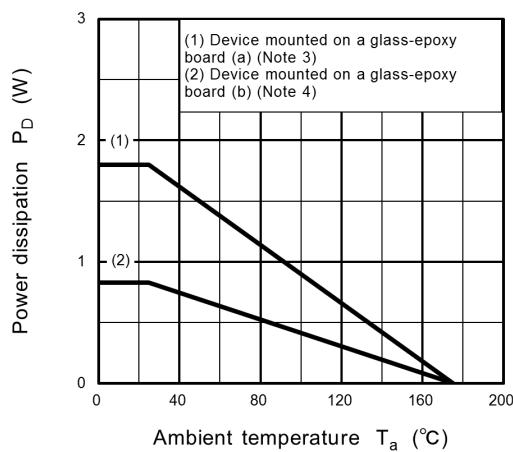
Fig. 8.7 $V_{(BR)DSS}$ - T_a Fig. 8.8 V_{th} - T_a Fig. 8.9 $R_{DS(ON)}$ - T_a 

Fig. 8.10 Dynamic Input/Output Characteristics

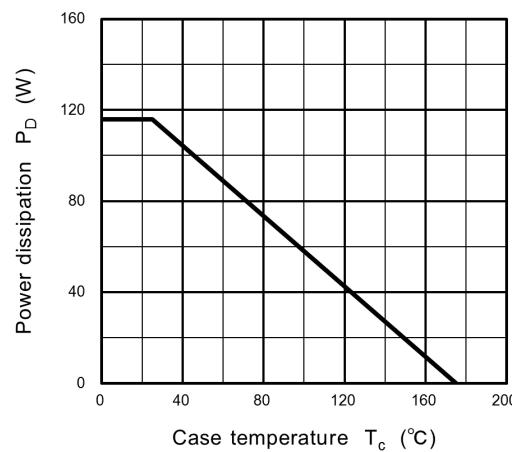
Fig. 8.11 Capacitance - V_{DS} Fig. 8.12 Q_{oss} - V_{DS}



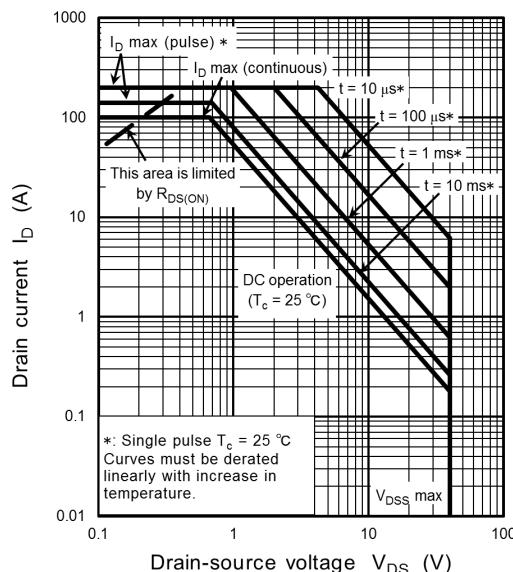
**Fig. 8.13 r_{th} - t_w
(Guaranteed Maximum)**



**Fig. 8.14 P_D - T_a
(Guaranteed Maximum)**



**Fig. 8.15 P_D - T_c
(Guaranteed Maximum)**

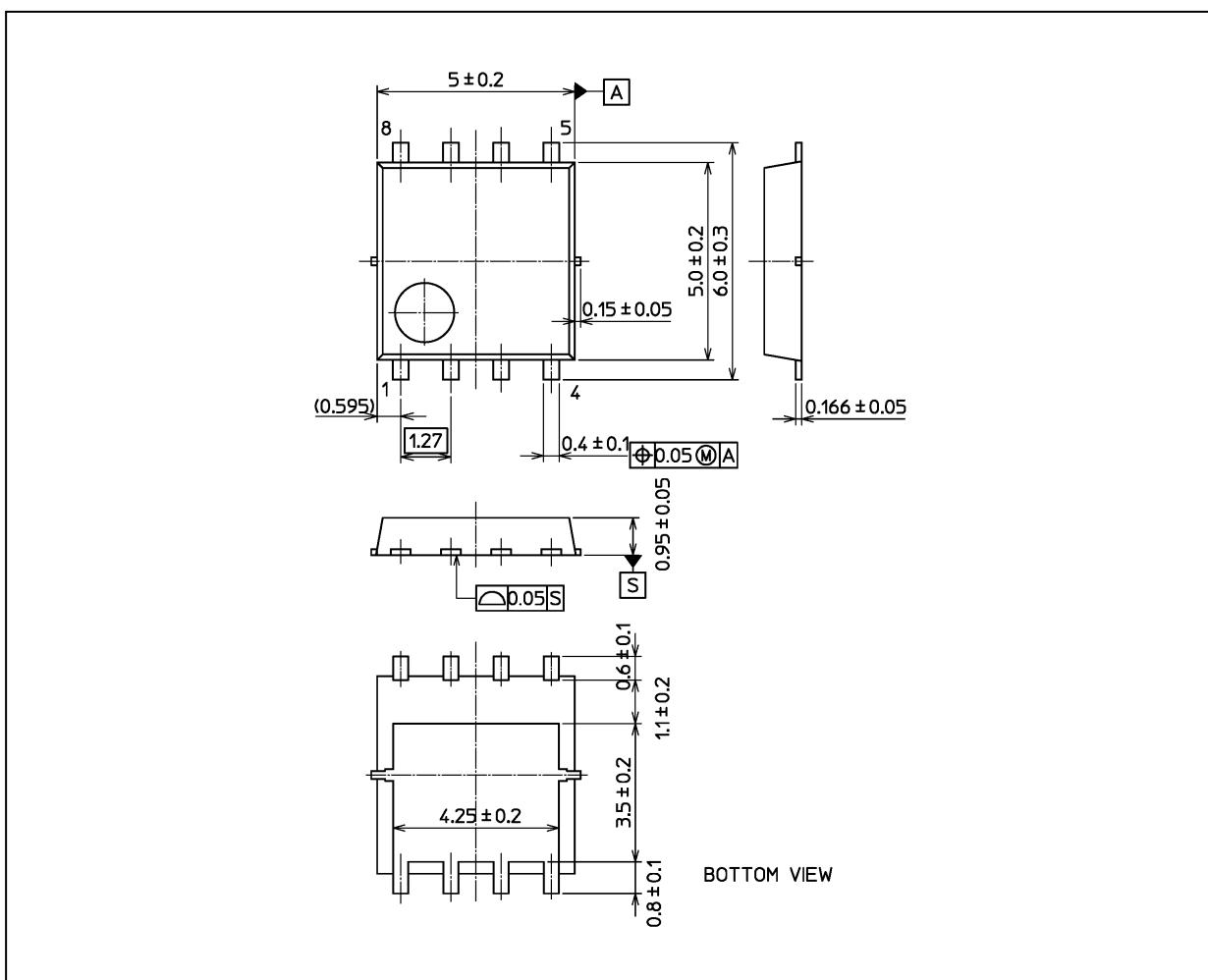


**Fig. 8.16 Safe Operating Area
(Guaranteed Maximum)**

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 0.069 g (typ.)

Package Name(s)
TOSHIBA: 2-5Q1S
Nickname: SOP Advance

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